

L Number	Hits	Search Text	DB	Time stamp
-	468	349/122	USPAT	2002/03/07 14:35
-	441	349/138	USPAT	2001/08/30 09:54
-	429	349/113	USPAT	2001/08/30 09:56
-	839	(passivation or dielectric) and (liquid adj crystal) and (change\$ with reflect\$) and thick\$	USPAT	2002/03/07 14:40
-	56	(passivation or dielectric) and (change\$ with reflect\$) and thick\$ and 349/113	USPAT	2001/08/30 10:44
-	19	(passivation or dielectric) and (change\$ with reflect\$) and thick\$ and 349/138	USPAT	2001/08/30 11:05
-	18	(passivation or dielectric) and (change\$ with reflect\$) and thick\$ and 349/122	USPAT	2001/08/30 11:15
-	503	349/122	USPAT	2002/03/07 14:37
-	483	349/138	USPAT	2002/03/07 14:38
-	490	349/149	USPAT	2002/03/07 14:39
-	939	349/42	USPAT	2002/03/07 14:39
-	616	349/43	USPAT	2002/03/07 14:39
-	11044	(passivation or dielectric) and (liquid adj crystal)	USPAT	2002/03/07 14:41
-	289	349/138 and ((passivation or dielectric) and (liquid adj crystal))	USPAT	2002/03/08 09:41
-	214	349/122 and ((passivation or dielectric) and (liquid adj crystal))	USPAT	2002/03/07 14:43
-	496	349/42 and ((passivation or dielectric) and (liquid adj crystal))	USPAT	2002/03/07 14:43
-	369	349/43 and ((passivation or dielectric) and (liquid adj crystal))	USPAT	2002/03/07 14:43
-	149	((passivation or dielectric) and (liquid adj crystal)) and (periphe\$4 adj region)	USPAT	2002/03/07 14:45
-	369	((passivation or dielectric) and (liquid adj crystal)) and (periphe\$4 adj circuit)) or ((passivation or dielectric) and (liquid adj crystal)) and (periphe\$4 adj region))	USPAT	2002/03/08 08:33
-	217	349/113 and ((passivation or dielectric) and (liquid adj crystal))	USPAT	2002/03/07 17:45
-	220	349/113 and (passivation or dielectric)	USPAT	2002/03/07 16:30
-	488	349/113	USPAT	2002/03/07 17:30
-	313	349/113 and ((passivation or dielectric or silicon) and (liquid adj crystal))	USPAT	2002/03/07 17:47
-	706	((passivation or dielectric or silicon)and(liquid adj crystal)) and ((periphe\$4 adj circuit)or(periphe\$4 adj region))	USPAT	2002/03/08 08:39
-	359	((passivation or dielectric or silicon)and(liquid adj crystal)) and ((periphe\$4 adj circuit)or(periphe\$4 adj region)) and panel	USPAT	2002/03/08 08:39
-	204	((passivation or dielectric or silicon)and(liquid adj crystal)) and ((periphe\$4 adj circuit)or(periphe\$4 adj region)) and panel and reflect\$6	USPAT	2002/03/08 08:40
-	12	((passivation or dielectric) and (liquid adj crystal)) and (periphery adj circuit)	USPAT	2002/03/08 09:14
-	235	((passivation or dielectric) and (liquid adj crystal)) and (periphe\$4 adj circuit)	USPAT	2002/03/08 09:15
-	179	349/138 and (passivation or dielectric or silicon) and (edge or periphery)	USPAT	2002/03/08 09:43
-	47	349/138 and (passivation or dielectric or silicon) and (edge or periphery)and seal	USPAT	2002/03/08 11:06
-	41	349/43 and (passivation or dielectric or silicon) and (edge or periphery)and seal	USPAT	2002/03/08 10:05
-	65	349/42 and (passivation or dielectric or silicon) and (edge or periphery)and seal	USPAT	2002/03/08 10:51
-	22	349/113 and (passivation or dielectric or silicon) and (edge or periphery)and seal	USPAT	2002/03/08 11:06
-	46	349/122 and (passivation or dielectric or silicon) and (edge or periphery)and seal	USPAT	2002/03/08 11:07
-	58	349/149 and (passivation or dielectric or silicon) and (edge or periphery)and seal	USPAT	2002/03/08 11:08
-	1	5056895.pn.	USPAT	2004/01/14 15:52
-	1	5978056.pn.	USPAT	2004/01/14 16:45

-	1	6344888.pn.	USPAT	2004/01/14 16:45
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